

SN54ABT620, SN74ABT620 OCTAL BUS TRANSCEIVERS WITH 3-STATE OUTPUTS

SCBS113D – FEBRUARY 1991 – REVISED APRIL 1998

- State-of-the-Art EPIC-II[™] BiCMOS Design Significantly Reduces Power Dissipation
- ESD Protection Exceeds 2000 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Latch-Up Performance Exceeds 500 mA Per JESD 17
- Typical V_{OLP} (Output Ground Bounce) < 1 V at $V_{CC} = 5$ V, $T_A = 25^\circ\text{C}$
- High-Drive Outputs (–32-mA I_{OH} , 64-mA I_{OL})
- Package Options Include Plastic Small-Outline (DW), Shrink Small-Outline (DB), and Thin Shrink Small-Outline (PW) Packages, Ceramic Chip Carriers (FK), and Plastic (N) and Ceramic (J) DIPs

description

These octal bus transceivers provide for asynchronous communication between data buses. The control-function implementation allows for maximum flexibility in timing. The 'ABT620 devices provide inverted data at the outputs.

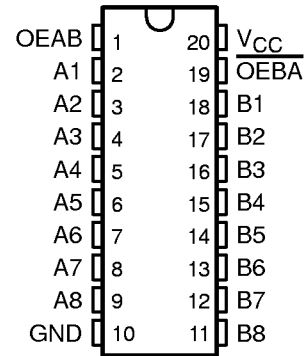
These devices allow data transmission from the A bus to the B bus or from the B bus to the A bus, depending on the logic levels at the output-enable ($\overline{\text{OEAB}}$ and $\overline{\text{OEBA}}$) inputs.

The output-enable inputs can be used to disable the device so that the buses are effectively isolated. The dual-enable configuration gives the transceivers the capability of storing data by simultaneously enabling $\overline{\text{OEAB}}$ and $\overline{\text{OEBA}}$. When both $\overline{\text{OEAB}}$ and $\overline{\text{OEBA}}$ are enabled and all other data sources to the two sets of bus lines are at high impedance, both sets of bus lines (16 total) remain at their last states. In this way, each output reinforces its input in this configuration.

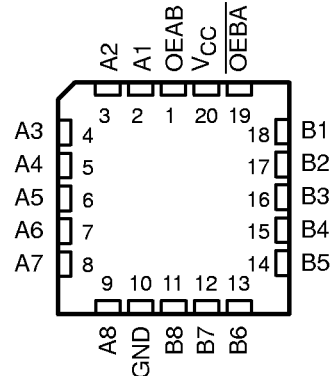
To ensure the high-impedance state during power up or power down, $\overline{\text{OEBA}}$ should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver. $\overline{\text{OEAB}}$ should be tied to GND through a pulldown resistor; the minimum value of the resistor is determined by the current-sourcing capability of the driver.

The SN54ABT620 is characterized for operation over the full military temperature range of -55°C to 125°C . The SN74ABT620 is characterized for operation from -40°C to 85°C .

SN54ABT620 . . . J PACKAGE
SN74ABT620 . . . DB, DW, N, OR PW PACKAGE
(TOP VIEW)



SN54ABT620 . . . FK PACKAGE
(TOP VIEW)



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recommended operating conditions (see Note 3)

			SN54ABT620		SN74ABT620		UNIT
			MIN	MAX	MIN	MAX	
V_{CC}	Supply voltage		4.5	5.5	4.5	5.5	V
V_{IH}	High-level input voltage		2		2		V
V_{IL}	Low-level input voltage			0.8		0.8	V
V_I	Input voltage		0	V_{CC}	0	V_{CC}	V
I_{OH}	High-level output current			-24		-32	mA
I_{OL}	Low-level output current			48		64	mA
$\Delta t/\Delta v$	Input transition rise or fall rate	Outputs enabled		5		5	ns/V
T_A	Operating free-air temperature		-55	125	-40	85	°C

NOTE 3: All unused pins (control or I/O) of the device must be held at V_{CC} or GND to ensure proper device operation. Refer to the TI application report, *Implications of Slow or Floating CMOS Inputs*, literature number SCBA004.

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electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER	TEST CONDITIONS		T _A = 25°C			SN54ABT620		SN74ABT620		UNIT	
			MIN	TYP†	MAX	MIN	MAX	MIN	MAX		
V _{IK}	V _{CC} = 4.5 V, I _I = -18 mA		-1.2			-1.2		-1.2		V	
V _{OH}	V _{CC} = 4.5 V, I _{OH} = -3 mA		2.5			2.5		2.5		V	
	V _{CC} = 5 V, I _{OH} = -3 mA		3			3		3			
	V _{CC} = 4.5 V	I _{OH} = -24 mA	2			2					
I _{OH} = -32 mA		2*					2				
V _{OL}	V _{CC} = 4.5 V		I _{OL} = 48 mA			0.55			V		
			I _{OL} = 64 mA			0.55*					
V _{hys}			100							mV	
I _I	Control inputs	V _{CC} = 5.5 V, V _I = V _{CC} or GND	±1			±1		±1		μA	
	A or B ports		±100			±100		±100			
I _{OZH} ‡	V _{CC} = 5.5 V, V _O = 2.7 V		50			50		50		μA	
I _{OZL} ‡	V _{CC} = 5.5 V, V _O = 0.5 V		-50			-50		-50		μA	
I _{off}	V _{CC} = 0, V _I or V _O ≤ 4.5 V		±100					±100		μA	
I _{CEX}	V _{CC} = 5.5 V, V _O = 5.5 V		Outputs high		50		50		50		μA
I _O §	V _{CC} = 5.5 V, V _O = 2.5 V		-50	-100	-180	-50	-180	-50	-180	mA	
I _{CC}	A or B ports	V _{CC} = 5.5 V, I _O = 0, V _I = V _{CC} or GND	Outputs high		5	250	250	250	250	μA	
			Outputs low		24	30	30	30	30	mA	
			Outputs disabled		0.5	250	250	250	250	μA	
ΔI _{CC} ¶	Data inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND	Outputs enabled		1.5		1.5		1.5		mA
			Outputs disabled		0.05		0.05		0.05		
	Control inputs	V _{CC} = 5.5 V, One input at 3.4 V, Other inputs at V _{CC} or GND		1.5		1.5		1.5			
C _i	Control inputs	V _I = 2.5 V or 0.5 V		4					pF		
C _{io}	A or B ports	V _O = 2.5 V or 0.5 V		7					pF		

* On products compliant to MIL-PRF-38535, this parameter does not apply.

† All typical values are at V_{CC} = 5 V.

‡ The parameters I_{OZH} and I_{OZL} include the input leakage current.

§ Not more than one output should be tested at a time, and the duration of the test should not exceed one second.

¶ This is the increase in supply current for each input that is at the specified TTL voltage level rather than V_{CC} or GND.

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switching characteristics over recommended ranges of supply voltage and operating free-air temperature, $C_L = 50$ pF (unless otherwise noted) (see Figure 1)

PARAMETER	FROM (INPUT)	TO (OUTPUT)	$V_{CC} = 5$ V, $T_A = 25^\circ$ C		SN54ABT620		SN74ABT620		UNIT
			MIN	MAX	MIN	MAX	MIN	MAX	
t_{PLH}	A or B	B or A	1	4.1	1		1	4.8	ns
t_{PHL}			1	4.3	1		1	4.8	
t_{PZH}	\overline{OEBA}	A	1.3	4.6	1.3		1.3	5.5	ns
t_{PZL}			1	6.1	1		1	7.1	
t_{PHZ}	\overline{OEBA}	A	2	6.3	2		2	7	ns
t_{PLZ}			1.4	5.4	1.4		1.4	5.8	
t_{PZH}	OEAB	B	1.6	6.2	1.6		1.6	6.8	ns
t_{PZL}			2	5.9	2		2	6.4	
t_{PHZ}	OEAB	B	1.2	5.6	1.2		1.2	6.5	ns
t_{PLZ}			1.1	4.7	1.1		1.1	5.6	

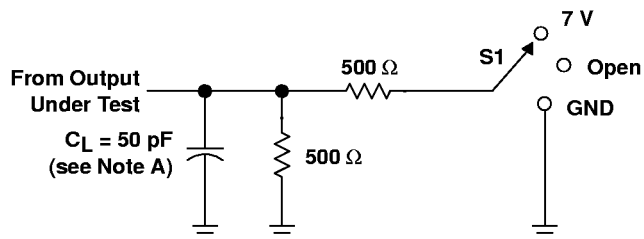
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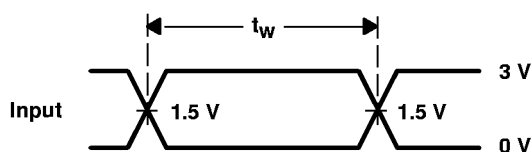
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PARAMETER MEASUREMENT INFORMATION

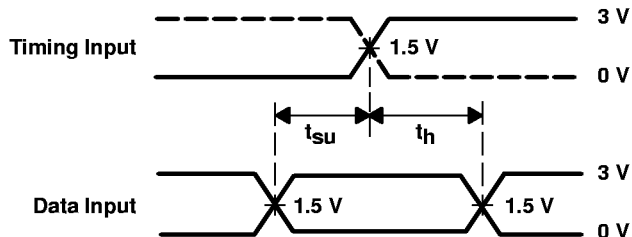


LOAD CIRCUIT

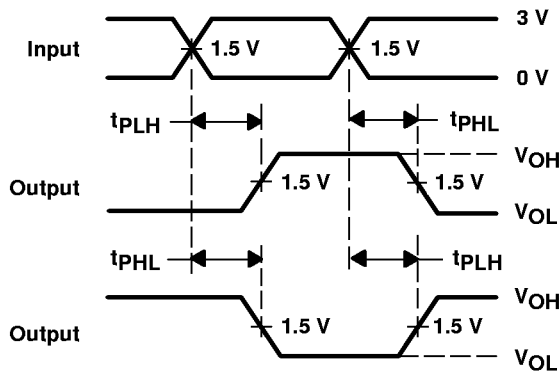
TEST	S1
t_{PLH}/t_{PHL}	Open
t_{PLZ}/t_{PZL}	7 V
t_{PHZ}/t_{PZH}	Open



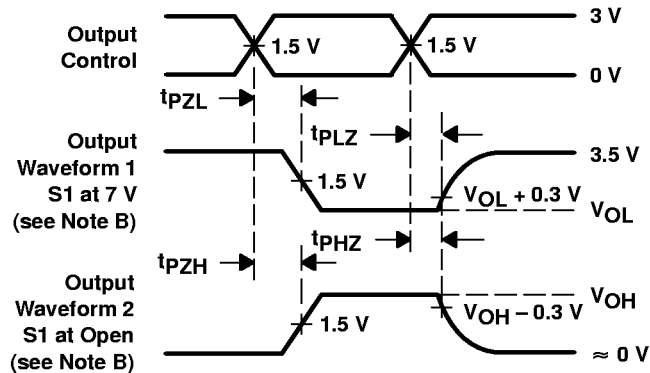
VOLTAGE WAVEFORMS
PULSE DURATION



VOLTAGE WAVEFORMS
SETUP AND HOLD TIMES



VOLTAGE WAVEFORMS
PROPAGATION DELAY TIMES
INVERTING AND NONINVERTING OUTPUTS



VOLTAGE WAVEFORMS
ENABLE AND DISABLE TIMES
LOW- AND HIGH-LEVEL ENABLING

- NOTES: A. C_L includes probe and jig capacitance.
 B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 C. All input pulses are supplied by generators having the following characteristics: $PRR \leq 10 \text{ MHz}$, $Z_O = 50 \Omega$, $t_r \leq 2.5 \text{ ns}$, $t_f \leq 2.5 \text{ ns}$.
 D. The outputs are measured one at a time with one transition per measurement.

Figure 1. Load Circuit and Voltage Waveforms

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